Low-power D-type flip-flop with set and reset; positive-edge trigger

Rev. 5 — 26 July 2010

Product data sheet

1. General description

The 74AUP1G74 provides a low-power, low-voltage single positive-edge triggered D-type flip-flop with individual data (D), clock (CP), set (SD) and reset (RD) inputs and complementary Q and \overline{Q} outputs. The SD and RD are asynchronous active LOW inputs and operate independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D input must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - ◆ JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \ \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C



Low-power D-type flip-flop with set and reset; positive-edge trigger

3. Ordering information

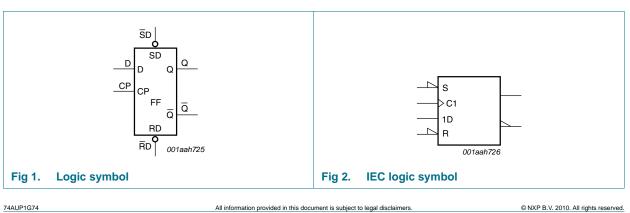
Table 1. Ordering	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G74DC	–40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP1G74GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1
74AUP1G74GF	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 \times 1 \times 0.5 mm	SOT1089
74AUP1G74GD	–40 °C to +125 °C	XSON8U	plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body $3 \times 2 \times 0.5$ mm	SOT996-2
74AUP1G74GM	–40 °C to +125 °C	XQFN8U	plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body $1.6 \times 1.6 \times 0.5$ mm	SOT902-1
74AUP1G74GN	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.2 \times 1.0 \times 0.35$ mm	SOT1116
74AUP1G74GS	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.35 \times 1.0 \times 0.35$ mm	SOT1203

4. Marking

Table 2. Marking codes	
Type number	Marking code ^[1]
74AUP1G74DC	p74
74AUP1G74GT	р74
74AUP1G74GF	54
74AUP1G74GD	р74
74AUP1G74GM	p74
74AUP1G74GN	54
74AUP1G74GS	54

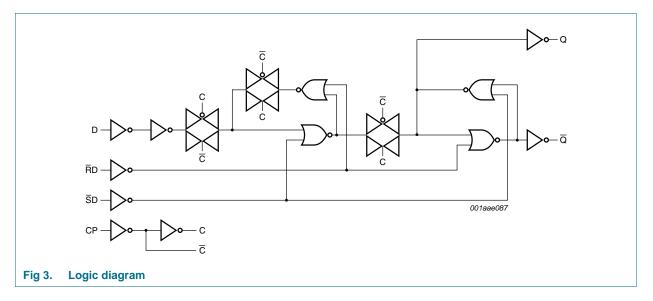
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



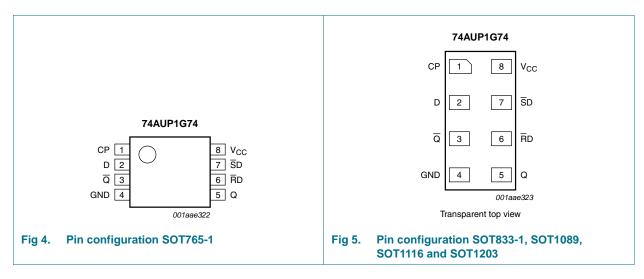
Product data sheet

Low-power D-type flip-flop with set and reset; positive-edge trigger



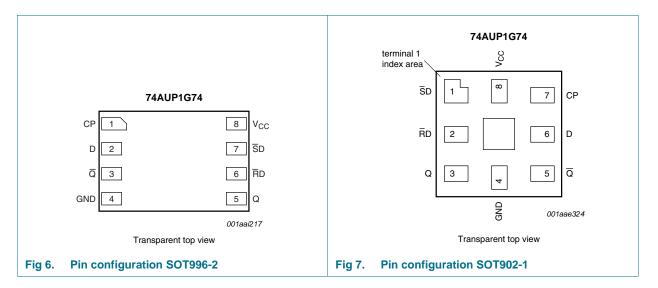
6. Pinning information





74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger



6.2 Pin description

Symbol	Pin	Pin				
CP D Q GND	SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203	SOT902-1				
CP	1	7	clock input			
D	2	6	data input			
Q	3	5	complement output			
GND	4	4	ground (0 V)			
Q	5	3	true output			
RD	6	2	asynchronous reset input (active LOW)			
SD	7	1	asynchronous set input (active LOW)			
V _{CC}	8	8	supply voltage			

7. Functional description

Table 4.	Function table for as					
Input				Output		
SD	RD	СР	D	Q	Q	
L	Н	x	Х	н	L	
Н	L	Х	Х	L	Н	
L	L	Х	Х	Н	Н	

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

		,				
Input				Output		
SD	RD	СР	D	Q _{n+1}	Q _{n+1}	
Н	Н	\uparrow	L	L	Н	
Н	Н	\uparrow	Н	Н	L	

Table 5. Function table for synchronous operation^[1]

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

 \uparrow = LOW-to-HIGH CP transition;

 Q_{n+1} = state after the next LOW-to-HIGH CP transition.

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

SymbolParameterConditionsMin V_{CC} supply voltage-0. I_{IK} input clamping current $V_I < 0 V$ -50 V_I input voltage11 -0.		,
I_{IK} input clamping current $V_I < 0 V$ -50	n Ma	x Unit
	5 +4.	6 V
V ₁ input voltage [1] -0.) -	mA
	5 +4.	6 V
I_{OK} output clamping current $V_O < 0 V$ -50) -	mA
V_{O} output voltage Active mode and Power-down mode [1] -0.	5 +4.	6 V
I_O output current $V_O = 0 V$ to V_{CC} -	±20) mA
I _{CC} supply current -	+50) mA
I _{GND} ground current -50) -	mA
T _{stg} storage temperature -65	5 +15	50 °C
P_{tot} total power dissipation $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2] -	250) mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For VSSOP8 packages: above 110 °C the value of Ptot derates linearly with 8.0 mW/K.

For XSON8, XSON8U and XQFN8U packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 7.	Operating conditions				
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$	-	200	ns/V

Low-power D-type flip-flop with set and reset; positive-edge trigger

10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
VIH	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu\text{A};V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3\times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.31	V
		$I_0 = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.31	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
	input leakage current	$V_{\rm I}$ = GND to 3.6 V; $V_{\rm CC}$ = 0 V to 3.6 V	-	-	±0.1	μA
OFF	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI_{OFF}	additional power-off leakage current		-	-	±0.2	μΑ
СС	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \text{ to } 3.6 \ V \end{array}$	-	-	0.5	μΑ
∆l _{CC}	additional supply current		<u>[1]</u> _	-	40	μΑ
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND or V_{CC}	-	0.6	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.3	-	pF

 74AUP1G74
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 Product data sheet
 Rev. 5 — 26 July 2010
 6 of 28

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = –	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		V_{CC} = 0.9 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V_{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V_{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = –20 $\mu A; V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_0 = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7\times V_{CC}$	-	-	V
		$I_0 = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		$I_0 = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	$0.3 \times V_{CC}$	V
		$I_0 = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	-	-	0.37	V
		$I_0 = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.35	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
OFF	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μΑ
∆I _{OFF}	additional power-off leakage current		-	-	±0.6	μA
СС	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μΑ
∆l _{CC}	additional supply current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{CC} - 0.6 \; V; \; I_{O} = 0 \; A; \\ V_{CC} = 3.3 \; V; \; per \; pin \end{array}$	<u>[1]</u> _	-	50	μA

Table 8. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.75\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 \text{ V}$ to 1.95 V	$0.70\times V_{CC}$	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.25\times V_{CC}$	V
		$V_{CC} = 0.9 \text{ V}$ to 1.95 V	-	-	$0.30\times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V_{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = –20 $\mu\text{A};V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.11$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.6 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.17	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		I_O = 20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I_{O} = 1.1 mA; V_{CC} = 1.1 V	-	-	$0.33 \times V_{CC}$	V
		I_{O} = 1.7 mA; V_{CC} = 1.4 V	-	-	0.41	V
		I_{O} = 1.9 mA; V_{CC} = 1.65 V	-	-	0.39	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.36	V
		I_{O} = 3.1 mA; V_{CC} = 2.3 V	-	-	0.50	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.36	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.50	V
I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
OFF	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μΑ
∆I _{OFF}	additional power-off leakage current		-	-	±0.75	μA
CC	supply current	$V_{I} = \text{GND or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
∆l _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}; \text{ per pin}$	<u>[1]</u> -	-	75	μA

Table 8. Static characteristics ... continued

[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

Low-power D-type flip-flop with set and reset; positive-edge trigger

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10.

Symbol	Parameter	Conditions		Tar	_{nb} = 25	°C	Tar	mb = -40 °	°C to +	125 °C	Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 5 p	F										•
t _{pd}	propagation	CP to Q, \overline{Q} ; see Figure 8	[2]								
	delay	$V_{CC} = 0.8 V$		-	25.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.9	6.7	14.0	2.6	14.2	2.6	14.2	ns
		V_{CC} = 1.4 V to 1.6 V		2.4	4.5	7.6	2.3	8.3	2.3	8.6	ns
		V_{CC} = 1.65 V to 1.95 V		1.9	3.5	5.7	1.7	6.5	1.7	6.8	ns
		V_{CC} = 2.3 V to 2.7 V		1.7	2.6	3.8	1.4	4.4	1.4	4.7	ns
		V_{CC} = 3.0 V to 3.6 V		1.5	2.2	3.1	1.2	3.4	1.2	3.7	ns
		\overline{SD} to Q, \overline{Q} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	19.6	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.7	5.6	11.0	2.5	11.4	2.5	11.5	ns
		V_{CC} = 1.4 V to 1.6 V		2.4	4.0	6.3	2.2	6.9	2.2	7.3	ns
		V_{CC} = 1.65 V to 1.95 V		2.0	3.3	4.9	1.7	5.6	1.7	5.9	ns
		V_{CC} = 2.3 V to 2.7 V		1.9	2.7	3.7	1.7	4.0	1.7	4.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.8	2.5	3.2	1.5	3.6	1.5	3.8	ns
		\overline{RD} to Q, \overline{Q} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	19.2	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.6	5.5	11.0	2.5	11.3	2.5	11.5	ns
		V_{CC} = 1.4 V to 1.6 V		2.3	3.9	6.3	2.2	6.8	2.2	7.3	ns
		V_{CC} = 1.65 V to 1.95 V		1.9	3.2	5.0	1.8	5.6	1.8	5.9	ns
		V_{CC} = 2.3 V to 2.7 V		1.9	2.6	3.6	1.7	4.1	1.7	4.3	ns
		V_{CC} = 3.0 V to 3.6 V		1.8	2.4	3.3	1.5	3.6	1.5	3.8	ns
f _{max}	maximum	CP; see Figure 9									
	frequency	$V_{CC} = 0.8 V$		-	53	-	-	-	-	-	MHz
		V_{CC} = 1.1 V to 1.3 V		-	203	-	170	-	170	-	MHz
		V_{CC} = 1.4 V to 1.6 V		-	347	-	310	-	300	-	MHz
		V_{CC} = 1.65 V to 1.95 V		-	435	-	400	-	390	-	MHz
		$V_{\rm CC}$ = 2.3 V to 2.7 V		-	550	-	490	-	480	-	MHz
		V_{CC} = 3.0 V to 3.6 V		-	619	-	550	-	510	-	MHz

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions		Tar	_{mb} = 25	°C	Tar	mb = -40 °	°C to +	125 °C	Uni
				Min	Typ <mark>[1]</mark>	Max	Min	Мах (85 °С)	Min	Max (125 °C)	
C _L = 10	pF										
^t pd	propagation	CP to Q, \overline{Q} ; see Figure 8	[2]								
	delay	$V_{CC} = 0.8 V$		-	28.9	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.1	7.5	15.8	2.9	16.1	2.9	16.1	ns
		V_{CC} = 1.4 V to 1.6 V		2.7	5.1	8.7	2.4	9.4	2.4	9.8	ns
		V_{CC} = 1.65 V to 1.95 V		2.5	4.1	6.5	2.2	7.2	2.2	7.6	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	3.2	4.6	1.8	5.3	1.8	5.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.8	2.8	3.8	1.6	4.1	1.6	4.4	ns
		\overline{SD} to Q, \overline{Q} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	23.2	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.9	6.5	12.9	2.8	13.3	2.8	13.5	ns
		V_{CC} = 1.4 V to 1.6 V		2.7	4.6	7.5	2.3	7.9	2.3	8.3	ns
		V_{CC} = 1.65 V to 1.95 V		2.6	3.9	5.6	2.3	6.3	2.3	6.6	ns
		V_{CC} = 2.3 V to 2.7 V		2.3	3.2	4.4	2.0	4.8	2.0	5.2	ns
		V_{CC} = 3.0 V to 3.6 V		2.2	3.0	3.9	1.9	4.2	1.9	4.4	ns
		\overline{RD} to Q, \overline{Q} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	22.7	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		2.8	6.4	12.8	2.7	13.2	2.7	13.4	ns
		V_{CC} = 1.4 V to 1.6 V		2.6	4.5	7.5	2.3	8.1	2.3	8.4	ns
		V_{CC} = 1.65 V to 1.95 V		2.5	3.3	5.8	2.3	6.3	2.3	6.7	ns
		V_{CC} = 2.3 V to 2.7 V		2.2	3.2	4.4	2.0	4.9	2.0	5.2	ns
		V_{CC} = 3.0 V to 3.6 V		2.0	2.9	4.0	1.9	4.3	1.9	4.5	ns
max	maximum	CP; see Figure 9									
	frequency	$V_{CC} = 0.8 V$		-	52	-	-	-	-	-	MH
		V_{CC} = 1.1 V to 1.3 V		-	192	-	150	-	150	-	MH
		V_{CC} = 1.4 V to 1.6 V		-	324	-	280	-	230	-	MH
		V_{CC} = 1.65 V to 1.95 V		-	421	-	310	-	250	-	MH
		V_{CC} = 2.3 V to 2.7 V		-	486	-	370	-	360	-	Мŀ

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 10</u>.

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions		Ta	_{nb} = 25	°C	T _{amb} = −40 °C to +125 °C				Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 15	pF										
t _{pd}	propagation	CP to Q, Q; see Figure 8	[2]								
	delay	$V_{CC} = 0.8 V$		-	32.4	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.5	8.3	17.6	3.3	17.8	3.3	18.0	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.2	5.6	9.5	2.8	10.5	2.8	11.1	ns
		V_{CC} = 1.65 V to 1.95 V		2.7	4.6	7.2	2.5	8.1	2.5	8.6	ns
		V_{CC} = 2.3 V to 2.7 V		2.4	3.6	5.2	2.2	5.8	2.2	6.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.2	3.2	4.4	2.0	4.9	2.0	5.2	ns
		SD to Q, Q; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	26.7	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.3	7.3	14.7	3.1	15.2	3.1	15.4	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		3.2	5.2	8.3	2.9	9.0	2.9	9.5	ns
		V_{CC} = 1.65 V to 1.95 V		2.8	4.3	6.4	2.5	7.1	2.5	7.5	ns
		V_{CC} = 2.3 V to 2.7 V		2.8	3.7	5.1	2.2	5.5	2.2	5.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.5	3.5	4.6	2.4	5.0	2.4	5.2	ns
	\overline{RD} to Q, \overline{Q} ; see Figure 9	[2]									
		$V_{CC} = 0.8 V$		-	26.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.2	7.2	14.5	3.1	15.0	3.1	15.2	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		3.1	5.1	8.4	2.7	9.2	2.7	9.7	ns
		V_{CC} = 1.65 V to 1.95 V		2.7	4.3	6.5	2.6	7.3	2.6	7.7	ns
		V_{CC} = 2.3 V to 2.7 V		2.6	3.6	5.0	2.4	5.5	2.4	5.8	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.4	3.4	4.6	2.3	5.0	2.3	5.2	ns
f _{max}	maximum	CP; see Figure 9									
	frequency	$V_{CC} = 0.8 V$		-	50	-	-	-	-	-	MHz
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		-	181	-	120	-	120	-	MHz
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		-	301	-	190	-	160	-	MHz
		V_{CC} = 1.65 V to 1.95 V		-	407	-	240	-	190	-	MHz
		V_{CC} = 2.3 V to 2.7 V		-	422	-	300	-	270	-	MHz
		V_{CC} = 3.0 V to 3.6 V		-	481	-	320	-	300	-	MHz

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10.

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions		Tai	_{mb} = 25	°C	Ta	mb = -40 °	°C to +	125 °C	Unit
					Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 30	pF										
t _{pd}	propagation	CP to Q, \overline{Q} ; see Figure 8	[2]								
	delay	$V_{CC} = 0.8 V$		-	42.7	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		4.2	10.6	22.5	4.0	23.0	4.0	23.3	ns
		V_{CC} = 1.4 V to 1.6 V		3.7	7.2	12.0	3.7	13.3	3.7	14.0	ns
		V_{CC} = 1.65 V to 1.95 V		3.5	5.8	9.2	3.4	10.4	3.4	11.0	ns
		V_{CC} = 2.3 V to 2.7 V		3.3	4.7	6.6	3.0	7.3	3.0	7.8	ns
		V_{CC} = 3.0 V to 3.6 V		3.0	4.3	5.8	2.8	6.8	2.8	7.3	ns
		\overline{SD} to Q, \overline{Q} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	37.0	-	-	-	-	-	ns
	V_{CC} = 1.1 V to 1.3 V		4.0	9.5	19.8	3.8	20.8	3.8	21.1	ns	
		V_{CC} = 1.4 V to 1.6 V		3.8	6.7	10.9	3.7	12.0	3.7	12.7	ns
		V_{CC} = 1.65 V to 1.95 V		3.7	5.6	8.4	3.5	9.3	3.5	9.9	ns
	V_{CC} = 2.3 V to 2.7 V		3.7	4.8	6.6	3.2	7.2	3.2	7.6	ns	
	V_{CC} = 3.0 V to 3.6 V		3.4	4.6	6.0	3.1	6.8	3.1	7.1	ns	
		\overline{RD} to Q, \overline{Q} ; see Figure 9	[2]								
		$V_{CC} = 0.8 V$		-	36.4	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V		3.9	9.4	19.5	3.8	20.2	3.8	20.5	ns
		V_{CC} = 1.4 V to 1.6 V		3.6	6.6	10.9	3.7	12.0	3.7	12.6	ns
		V_{CC} = 1.65 V to 1.95 V		3.5	5.5	8.5	3.5	9.5	3.5	10.1	ns
		V_{CC} = 2.3 V to 2.7 V		3.5	4.7	6.5	3.2	7.1	3.2	7.6	ns
		V_{CC} = 3.0 V to 3.6 V		3.3	4.4	6.1	3.1	7.1	3.1	7.5	ns
max	maximum	CP; see Figure 9									
	frequency	$V_{CC} = 0.8 V$		-	28	-	-	-	-	-	MH
		V_{CC} = 1.1 V to 1.3 V		-	145	-	70	-	70	-	MH
		V_{CC} = 1.4 V to 1.6 V		-	185	-	120	-	110	-	MH
		V_{CC} = 1.65 V to 1.95 V		-	270	-	150	-	120	-	MH
		$V_{\rm CC}$ = 2.3 V to 2.7 V		-	290	-	190	-	170	-	Мŀ
		V_{CC} = 3.0 V to 3.6 V		-	315	-	200	-	190	-	МH

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 10</u>.

Low-power D-type flip-flop with set and reset; positive-edge trigger

Voltages	are referenced to	GND (ground = 0 V); for test circu	it see <mark>F</mark>	Figure 10	<u>2</u> .					
Symbol Para	Parameter	Conditions	Ta	_{mb} = 25	°C	T_{amb} = -40 °C to +125 °C				Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Min	Max (125 °C)	
C _L = 5 pl	F, 10 pF, 15 pF an	d 30 pF								
t _{su}	set-up time	D to CP HIGH; see <u>Figure 8</u>								
		V _{CC} = 0.8 V	-	3.4	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	-	0.6	-	1.2	-	1.2	-	ns
		V_{CC} = 1.4 V to 1.6 V	-	0.3	-	0.6	-	0.6	-	ns
		V_{CC} = 1.65 V to 1.95 V	-	0.4	-	0.5	-	0.5	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	0.2	-	0.4	-	0.4	-	ns
		V_{CC} = 3.0 V to 3.6 V	-	0.3	-	0.4	-	0.4	-	ns
		D to CP LOW; see <u>Figure 8</u>								
		V _{CC} = 0.8 V	-	3.0	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	-	0.5	-	1.2	-	1.2	-	ns
		V_{CC} = 1.4 V to 1.6 V	-	0.3	-	0.7	-	0.7	-	ns
		V_{CC} = 1.65 V to 1.95 V	-	0.4	-	0.7	-	0.7	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	0.5	-	0.7	-	0.7	-	ns
		V_{CC} = 3.0 V to 3.6 V	-	0.6	-	0.8	-	0.8	-	ns
t _h	n hold time	D to CP; see Figure 8								
		$V_{CC} = 0.8 V$	-	-1.9	-	-	-	-	-	ns
		V_{CC} = 1.1 V to 1.3 V	-	-0.3	-	0.5	-	0.5	-	ns
		V_{CC} = 1.4 V to 1.6 V	-	-0.2	-	0.2	-	0.2	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.2	-	0.1	-	0.1	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.1	-	0.1	-	ns
		V_{CC} = 3.0 V to 3.6 V	-	-0.2	-	0.1	-	0.1	-	ns
t _{rec}	recovery time	RD; see Figure 9								
		V_{CC} = 1.1 V to 1.3 V	-	-0.5	-	-0.9	-	-0.9	-	ns
		V_{CC} = 1.4 V to 1.6 V	-	-0.2	-	-0.6	-	-0.6	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.2	-	-0.4	-	-0.4	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	-0.1	-	-0.1	-	-0.1	-	ns
		V_{CC} = 3.0 V to 3.6 V	-	-0.1	-	-0.1	-	-0.1	-	ns
		SD; see Figure 9								
		V_{CC} = 1.1 V to 1.3 V	-	-0.5	-	-0.3	-	-0.3	-	ns
		V_{CC} = 1.4 V to 1.6 V	-	-0.4	-	-0.1	-	-0.1	-	ns
		V_{CC} = 1.65 V to 1.95 V	-	-0.3	-	0	-	0	-	ns
		$V_{\rm CC}$ = 2.3 V to 2.7 V	-	-0.2	-	0.1	-	0.1	-	ns
		V_{CC} = 3.0 V to 3.6 V	-	-0.1	-	0.1	-	0.1	-	ns

Table 9.

Dynamic characteristics ...continued referenced to GND (around = 0 V): for test circuit see Figure 10. Valta

Low-power D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions		_{mb} = 25	°C	T _{amb} = −40 °C to +125 °C				Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Min	Max (125 °C)	
t _W	pulse width	CP HIGH or LOW; see <u>Figure 8</u>								
		V_{CC} = 1.1 V to 1.3 V	-	2.1	-	2.7	-	2.7	-	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	1.1	-	1.5	-	1.5	-	ns
		V_{CC} = 1.65 V to 1.95 V	-	0.9	-	1.6	-	1.6	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	0.6	-	1.7	-	1.7	-	ns
		V_{CC} = 3.0 V to 3.6 V	-	0.6	-	1.9	-	1.9	-	ns
		SD or RD LOW; see <u>Figure 9</u>								
		V_{CC} = 1.1 V to 1.3 V	-	4.2	-	11.3	-	11.5	-	ns
		V_{CC} = 1.4 V to 1.6 V	-	2.3	-	6.2	-	6.4	-	ns
		V_{CC} = 1.65 V to 1.95 V	-	1.8	-	4.8	-	5.0	-	ns
		V_{CC} = 2.3 V to 2.7 V	-	1.2	-	3.3	-	3.5	-	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	1.1	-	2.6	-	2.8	-	ns
C _{PD}	power dissipation	$f_i = 1 \text{ MHz};$ [3] $V_I = \text{GND to } V_{\text{CC}}$								
	capacitance	$V_{CC} = 0.8 V$	-	2.8	-	-	-	-	-	pF
		V_{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V_{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V_{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V_{CC} = 3.0 V to 3.6 V	-	3.9	-	-	-	-	-	pF

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 10</u>.

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

Low-power D-type flip-flop with set and reset; positive-edge trigger

12. Waveforms

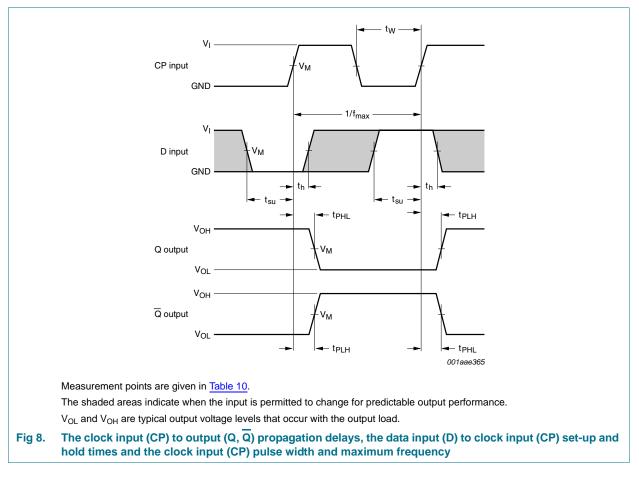
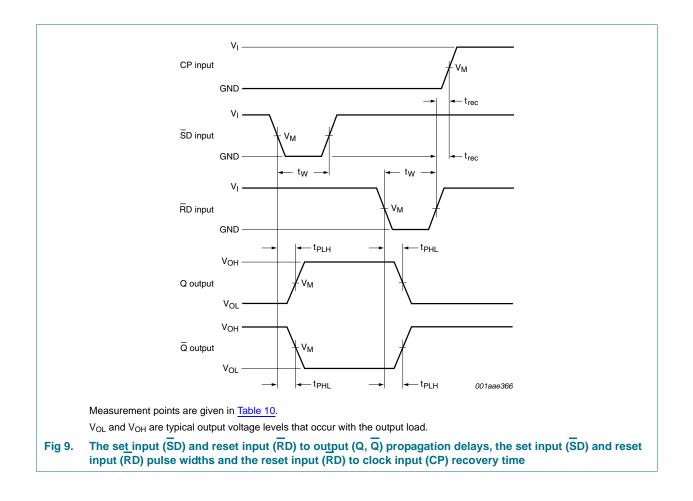


Table 10. Measurement points

Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	$t_r = t_f$
0.8 V to 3.6 V	$0.5 imes V_{CC}$	$0.5 imes V_{CC}$	V _{CC}	≤ 3.0 ns

74AUP1G74

Low-power D-type flip-flop with set and reset; positive-edge trigger



Low-power D-type flip-flop with set and reset; positive-edge trigger

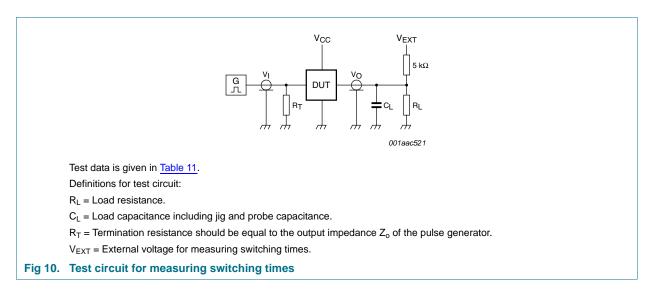


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

Low-power D-type flip-flop with set and reset; positive-edge trigger

13. Package outline

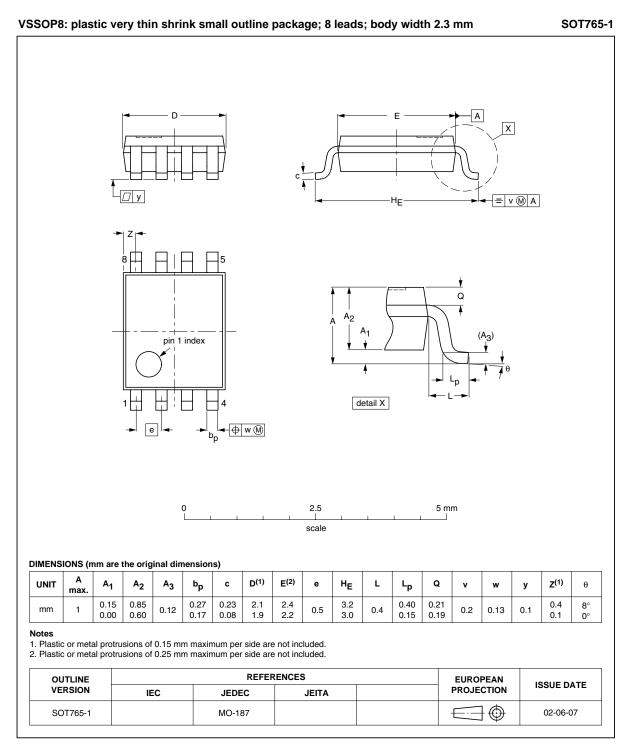


Fig 11. Package outline SOT765-1 (VSSOP8)

Low-power D-type flip-flop with set and reset; positive-edge trigger

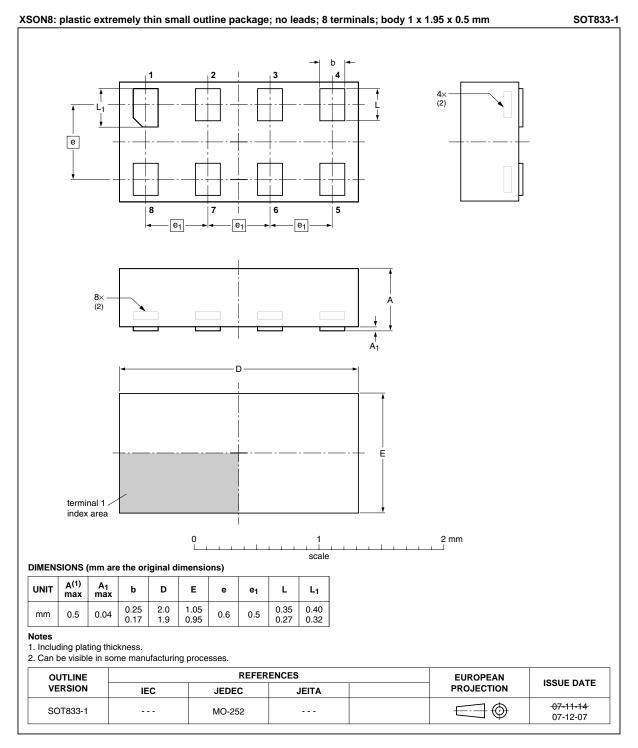
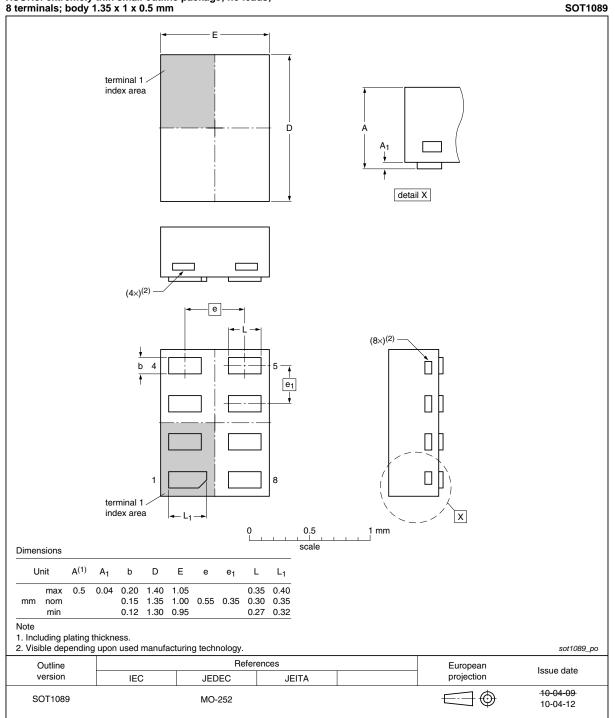


Fig 12. Package outline SOT833-1 (XSON8)

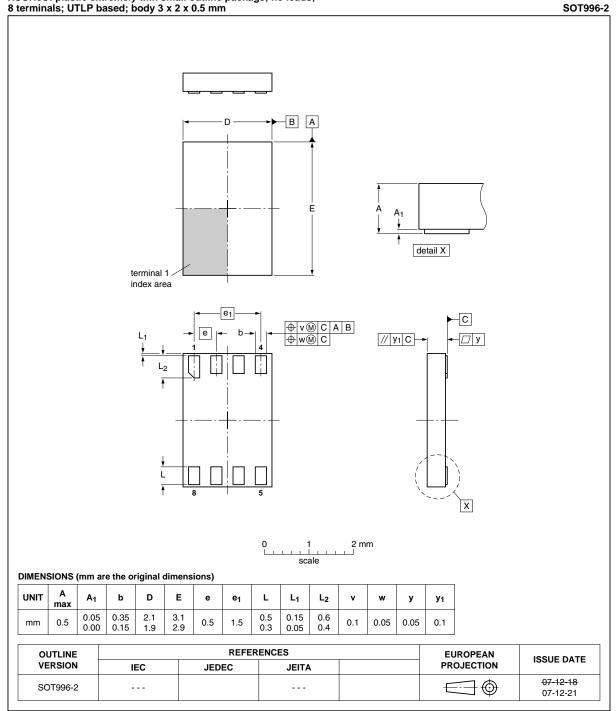
Low-power D-type flip-flop with set and reset; positive-edge trigger



XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig 13. Package outline SOT1089 (XSON8)

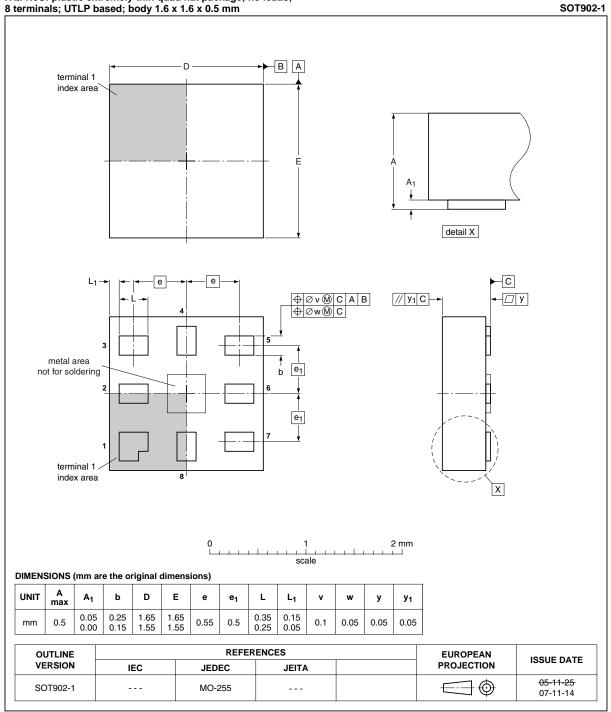
Low-power D-type flip-flop with set and reset; positive-edge trigger



XSON8U: plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body 3 x 2 x 0.5 mm

Fig 14. Package outline SOT996-2 (XSON8U)

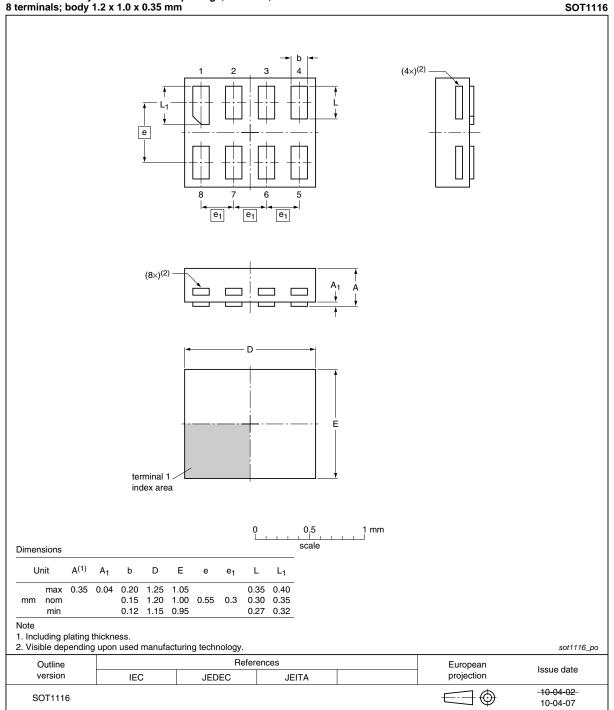
Low-power D-type flip-flop with set and reset; positive-edge trigger



XQFN8U: plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body 1.6 x 1.6 x 0.5 mm

Fig 15. Package outline SOT902-1 (XQFN8U)

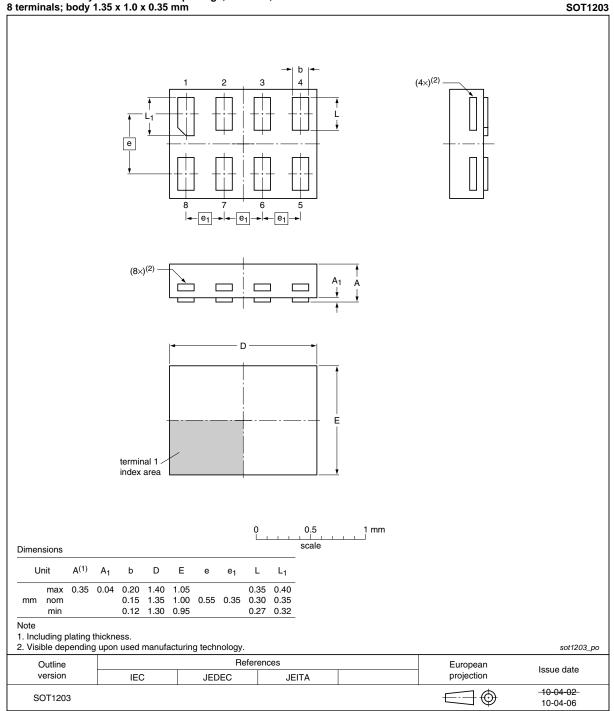
Low-power D-type flip-flop with set and reset; positive-edge trigger



XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm $\,$

Fig 16. Package outline SOT1116 (XSON8)

Low-power D-type flip-flop with set and reset; positive-edge trigger



XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm

Fig 17. Package outline SOT1203 (XSON8)

Low-power D-type flip-flop with set and reset; positive-edge trigger

14. Abbreviations

AcronymDescriptionCDMCharged Device ModelDUTDevice Under TestESDElectroStatic DischargeHBMHuman Body ModelMMMachine Model	Table 12. Abb	reviations	
DUTDevice Under TestESDElectroStatic DischargeHBMHuman Body Model	Acronym	Description	
ESD ElectroStatic Discharge HBM Human Body Model	CDM	Charged Device Model	
HBM Human Body Model	DUT	Device Under Test	
	ESD	ElectroStatic Discharge	
MM Machine Model	HBM	Human Body Model	
	MM	Machine Model	

15. Revision history

Table 13. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G74 v.5	20100726	Product data sheet	-	74AUP1G74 v.4
Modifications:	Added type r	number 74AUP1G74GF (SOT1 number 74AUP1G74GN (SOT1 number 74AUP1G74GS (SOT1	1116/XSON8 packag	e).
74AUP1G74 v.4	20080603	Product data sheet	-	74AUP1G74 v.3
74AUP1G74 v.3	20080207	Product data sheet	-	74AUP1G74 v.2
74AUP1G74 v.2	20070515	Product data sheet	-	74AUP1G74 v.1
74AUP1G74 v.1	20060825	Product data sheet	-	-

Low-power D-type flip-flop with set and reset; positive-edge trigger

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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18. Contents

1	General description 1
2	Features and benefits 1
3	Ordering information 2
4	Marking 2
5	Functional diagram 2
6	Pinning information 3
6.1 6.2	Pinning 3 Pin description 4
7	Functional description 4
8	Limiting values 5
9	Recommended operating conditions 5
10	Static characteristics 6
11	Dynamic characteristics 9
12	Waveforms 15
13	Package outline 18
14	Abbreviations 25
15	Revision history 25
16	Legal information 26
16.1	Data sheet status 26
16.2	Definitions 26
16.3	Disclaimers
16.4	Trademarks
17	Contact information 27
18	Contents

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